

DATA SHEET

74LVC32A Quad 2-input OR gate

Product specification
Supersedes data of 1997 Jun 30

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Philips
Semiconductors



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Quad 2-input OR gate

74LVC32A

FEATURES

- 5 V tolerant inputs for interfacing with 5 V logic
- Wide supply voltage range from 1.2 to 3.6 V
- CMOS low power consumption
- Direct interface with TTL levels
- Inputs accept voltages up to 5.5 V
- Complies with JEDEC standard no. 8-1A
- ESD protection:
HBM EIA/JESD22-A114-A exceeds 2000 V
MM EIA/JESD22-A115-A exceeds 200 V.
- Specified from -40 to $+85$ °C and -40 to $+125$ °C.

DESCRIPTION

The 74LVC32A is a high-performance, low-power, low-voltage, Si-gate CMOS device, superior to most advanced CMOS compatible TTL families.

Inputs can be driven from either 3.3 or 5 V devices. This feature allows the use of these devices as translators in a mixed 3.3 and 5 V environment.

The 74LVC32A provides the 2-input OR function.

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25$ °C; $t_r = t_f \leq 2.5$ ns.

| SYMBOL | PARAMETER | CONDITIONS | TYPICAL | UNIT |
|-------------------|--|---------------------------------|---------|------|
| t_{PHL}/t_{PLH} | propagation delay nA, nB to nY | $C_L = 50$ pF; $V_{CC} = 3.3$ V | 2.1 | ns |
| C_i | input capacitance | | 4.0 | pF |
| C_{PD} | power dissipation capacitance per gate | $V_{CC} = 3.3$ V; notes 1 and 2 | 15 | pF |

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in Volts;

N = total load switching outputs;

$\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

2. The condition is $V_i = \text{GND}$ to V_{CC} .

ORDERING INFORMATION

| TYPE NUMBER | PACKAGE | | | | |
|-------------|--------------------|------|----------|----------|----------|
| | TEMPERATURE RANGE | PINS | PACKAGE | MATERIAL | CODE |
| 74LVC32AD | -40 to $+125$ °C | 14 | SO14 | plastic | SOT108-1 |
| 74LVC32ADB | -40 to $+125$ °C | 14 | SSOP14 | plastic | SOT337-1 |
| 74LVC32APW | -40 to $+125$ °C | 14 | TSSOP14 | plastic | SOT402-1 |
| 74LVC32ABQ | -40 to $+125$ °C | 14 | DHVQFN14 | plastic | SOT762-1 |

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FUNCTION TABLE

See note 1.

| INPUT | | OUTPUT |
|-------|----|--------|
| nA | nB | nY |
| L | L | L |
| L | H | H |
| H | L | H |
| H | H | H |

Note

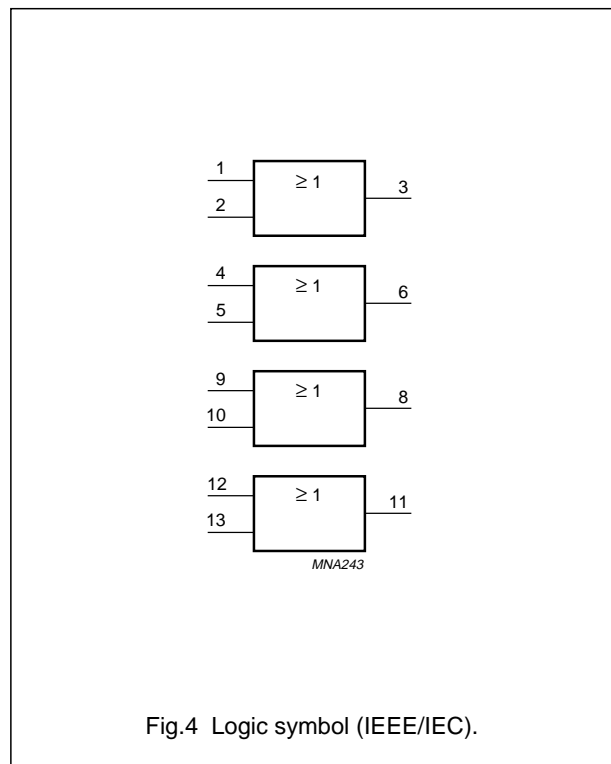
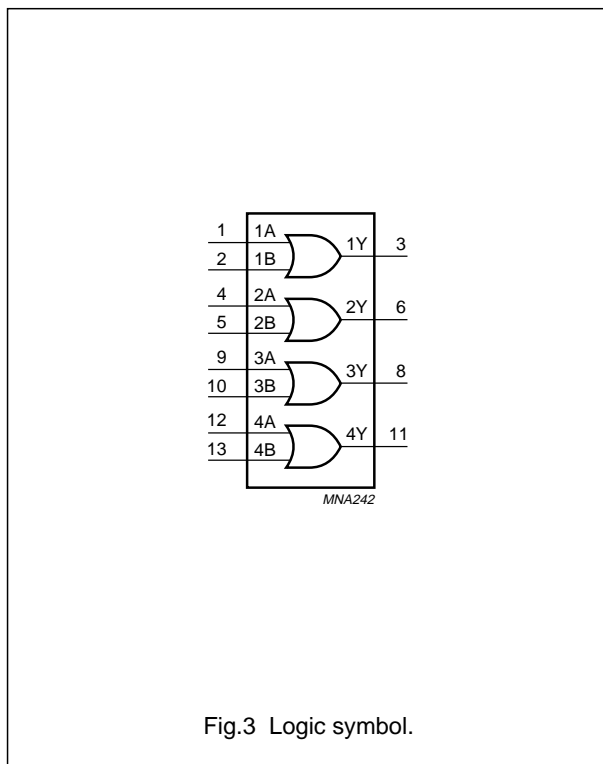
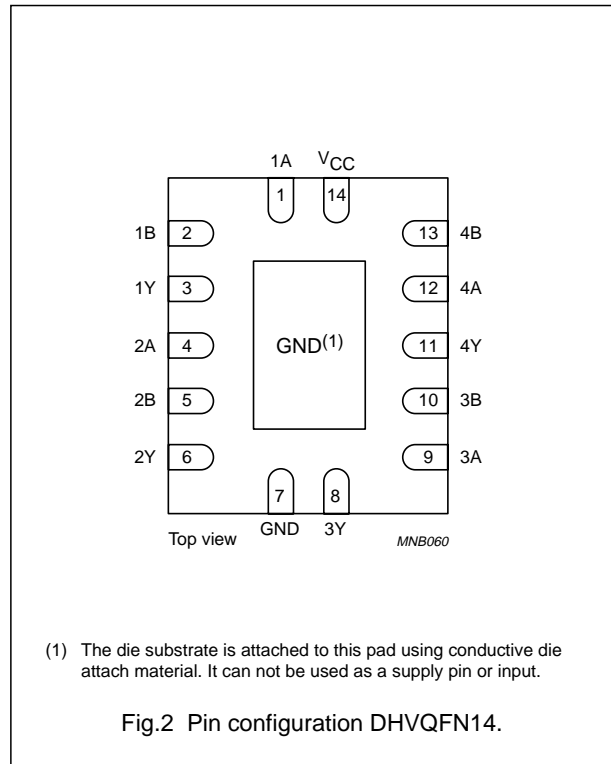
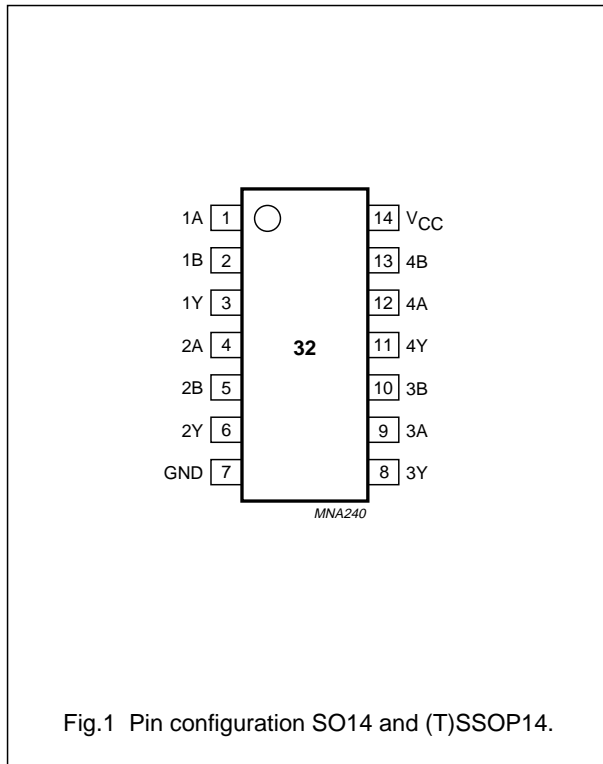
1. H = HIGH voltage level;
L = LOW voltage level.

PINNING

| PIN | SYMBOL | DESCRIPTION |
|-----|-----------------|----------------|
| 1 | 1A | data input |
| 2 | 1B | data input |
| 3 | 1Y | data output |
| 4 | 2A | data input |
| 5 | 2B | data input |
| 6 | 2Y | data output |
| 7 | GND | ground (0 V) |
| 8 | 3Y | data output |
| 9 | 3A | data input |
| 10 | 3B | data input |
| 11 | 4Y | data output |
| 12 | 4A | data input |
| 13 | 4B | data input |
| 14 | V _{CC} | supply voltage |

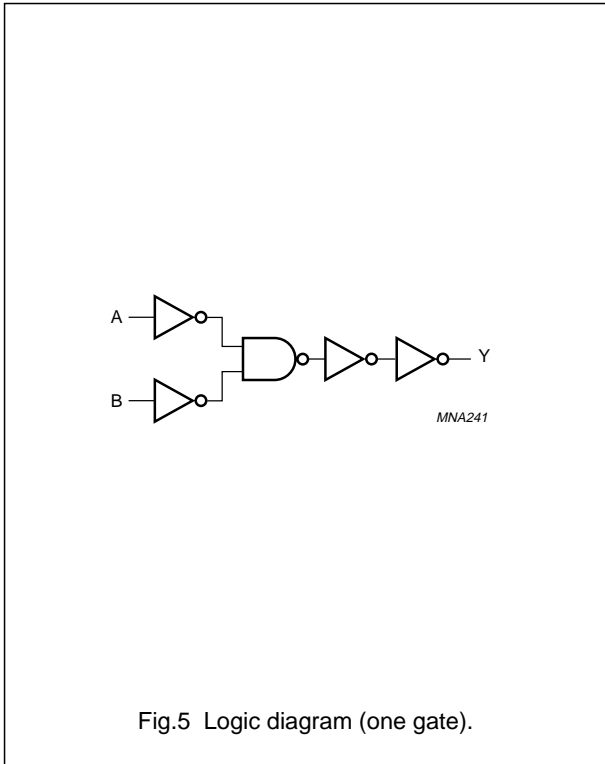
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RECOMMENDED OPERATING CONDITIONS

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------|-------------------------------|-------------------------------|------|----------|------|
| V_{CC} | supply voltage | for maximum speed performance | 2.7 | 3.6 | V |
| | | for low voltage applications | 1.2 | 3.6 | V |
| V_I | input voltage | | 0 | 5.5 | V |
| V_O | output voltage | | 0 | V_{CC} | V |
| T_{amb} | operating ambient temperature | | -40 | +125 | °C |
| t_r, t_f | input rise and fall times | $V_{CC} = 1.2$ to 2.7 V | 0 | 20 | ns/V |
| | | $V_{CC} = 2.7$ to 3.6 V | 0 | 10 | ns/V |

LIMITING VALUES

In accordance with the absolute maximum rating system (IEC 60134); voltages are referenced to GND (ground = 0 V).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|-------------------|-------------------------------|-------------------------------------|------|----------------|------|
| V_{CC} | supply voltage | | -0.5 | +6.5 | V |
| I_{IK} | input diode current | $V_I < 0$ | - | -50 | mA |
| V_I | input voltage | note 1 | -0.5 | +6.5 | V |
| I_{OK} | output diode current | $V_O > V_{CC}$ or $V_O < 0$ | - | ± 50 | mA |
| V_O | output voltage | note 1 | -0.5 | $V_{CC} + 0.5$ | V |
| I_O | output source or sink current | $V_O = 0$ to V_{CC} | - | ± 50 | mA |
| I_{CC}, I_{GND} | V_{CC} or GND current | | - | ± 100 | mA |
| T_{stg} | storage temperature | | -65 | +150 | °C |
| P_{tot} | power dissipation | $T_{amb} = -40$ to $+85$ °C; note 2 | - | 500 | mW |

Notes

- The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
- For SO14 packages: above 70 °C derate linearly with 8 mW/K.
For SSOP14 and TSSOP14 packages: above 60 °C derate linearly with 5.5 mW/K.
For DHVQFN14 packages: above 60 °C derate linearly with 4.5 mW/K.

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DC CHARACTERISTICS

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| SYMBOL | PARAMETER | TEST CONDITIONS | | MIN. | TYP. ⁽¹⁾ | MAX. | UNIT |
|--|---|--|---------------------|-----------------------|---------------------|------|------|
| | | OTHER | V _{CC} (V) | | | | |
| T_{amb} = -40 to +85 °C | | | | | | | |
| V _{IH} | HIGH-level input voltage | | 1.2 | V _{CC} | - | - | V |
| | | | 2.7 to 3.6 | 2.0 | - | - | V |
| V _{IL} | LOW-level input voltage | | 1.2 | - | - | GND | V |
| | | | 2.7 to 3.6 | - | - | 0.8 | V |
| V _{OH} | HIGH-level output voltage | V _I = V _{IH} or V _{IL} | 2.7 to 3.6 | V _{CC} - 0.2 | - | - | V |
| | | I _O = -100 μA | 2.7 | V _{CC} - 0.5 | - | - | V |
| | | I _O = -12 mA | 3.0 | V _{CC} - 0.6 | - | - | V |
| | | I _O = -24 mA | 3.0 | V _{CC} - 0.8 | - | - | V |
| V _{OL} | LOW-level output voltage | V _I = V _{IH} or V _{IL} | 2.7 to 3.6 | - | - | 0.2 | V |
| | | I _O = 100 μA | 2.7 | - | - | 0.4 | V |
| | | I _O = 24 mA | 3.0 | - | - | 0.55 | V |
| I _{LI} | input leakage current | V _I = 5.5 V or GND | 3.6 | - | ±0.1 | ±5 | μA |
| I _{CC} | quiescent supply current | V _I = V _{CC} or GND; I _O = 0 | 3.6 | - | 0.1 | 10 | μA |
| ΔI _{CC} | additional quiescent supply current per input pin | V _I = V _{CC} - 0.6V; I _O = 0 | 2.7 to 3.6 | - | 5 | 500 | μA |

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| SYMBOL | PARAMETER | TEST CONDITIONS | | MIN. | TYP. ⁽¹⁾ | MAX. | UNIT |
|---|---|--|---------------------|------------------------|---------------------|------|------|
| | | OTHER | V _{CC} (V) | | | | |
| T_{amb} = -40 to +125 °C | | | | | | | |
| V _{IH} | HIGH-level input voltage | | 1.2 | V _{CC} | – | – | V |
| | | | 2.7 to 3.6 | 2.0 | – | – | V |
| V _{IL} | LOW-level input voltage | | 1.2 | – | – | GND | V |
| | | | 2.7 to 3.6 | – | – | 0.8 | V |
| V _{OH} | HIGH-level output voltage | V _I = V _{IH} or V _{IL} | | | | | |
| | | I _O = -100 μA | 2.7 to 3.6 | V _{CC} - 0.3 | – | – | V |
| | | I _O = -12 mA | 2.7 | V _{CC} - 0.65 | – | – | V |
| | | I _O = -18 mA | 3.0 | V _{CC} - 0.75 | – | – | V |
| V _{OL} | LOW-level output voltage | V _I = V _{IH} or V _{IL} | | | | | |
| | | I _O = 100 μA | 2.7 to 3.6 | – | – | 0.3 | V |
| | | I _O = 12 mA | 2.7 | – | – | 0.6 | V |
| | | I _O = 24 mA | 3.0 | – | – | 0.8 | V |
| I _{LI} | input leakage current | V _I = 5.5 V or GND | 3.6 | – | – | ±20 | μA |
| I _{CC} | quiescent supply current | V _I = V _{CC} or GND; I _O = 0 | 3.6 | – | – | 40 | μA |
| ΔI _{CC} | additional quiescent supply current per input pin | V _I = V _{CC} - 0.6V; I _O = 0 | 2.7 to 3.6 | – | – | 5000 | μA |

Note

1. All typical values are at V_{CC} = 3.3 V and T_{amb} = 25 °C.

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AC CHARACTERISTICSGND = 0 V; $t_r = t_f \leq 2.5$ ns.

| SYMBOL | PARAMETER | TEST CONDITIONS | | MIN. | TYP. ⁽¹⁾ | MAX. | UNIT |
|---|--------------------------------|------------------|---------------------|------|---------------------|------|------|
| | | WAVEFORMS | V _{CC} (V) | | | | |
| T_{amb} = -40 to +85 °C | | | | | | | |
| t _{PHL} /t _{PLH} | propagation delay nA, nB to nY | see Figs 6 and 7 | 1.2 | – | 10 | – | ns |
| | | | 2.7 | 1.5 | 2.4 | 4.4 | ns |
| | | | 3.0 to 3.6 | 1.0 | 2.1 | 3.8 | ns |
| t _{sk(0)} | skew | note 2 | 3.0 to 3.6 | – | – | 1.0 | ns |
| T_{amb} = -40 to +125 °C | | | | | | | |
| t _{PHL} /t _{PLH} | propagation delay nA, nB to nY | see Figs 6 and 7 | 1.2 | – | – | – | ns |
| | | | 2.7 | 1.5 | – | 5.5 | ns |
| | | | 3.0 to 3.6 | 1.0 | – | 5.0 | ns |
| t _{sk(0)} | skew | note 2 | 3.0 to 3.6 | – | – | 1.5 | ns |

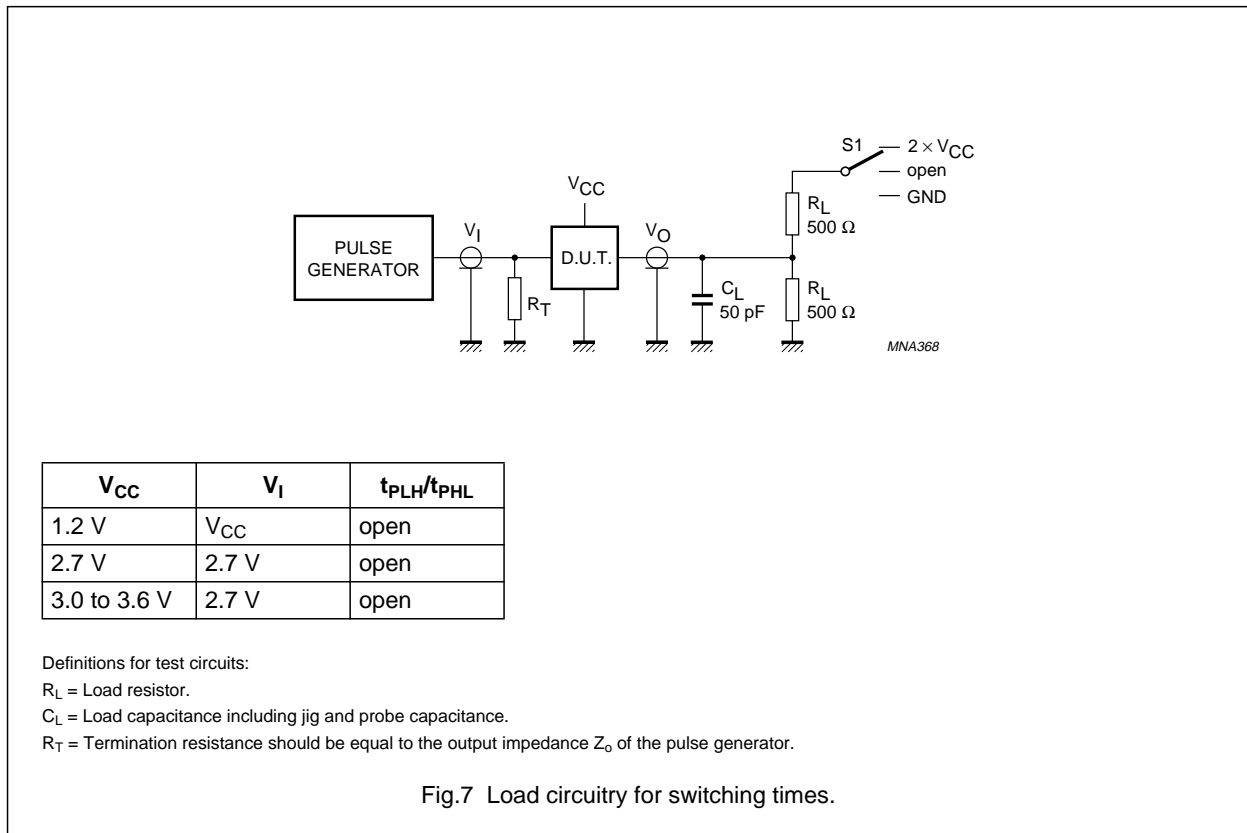
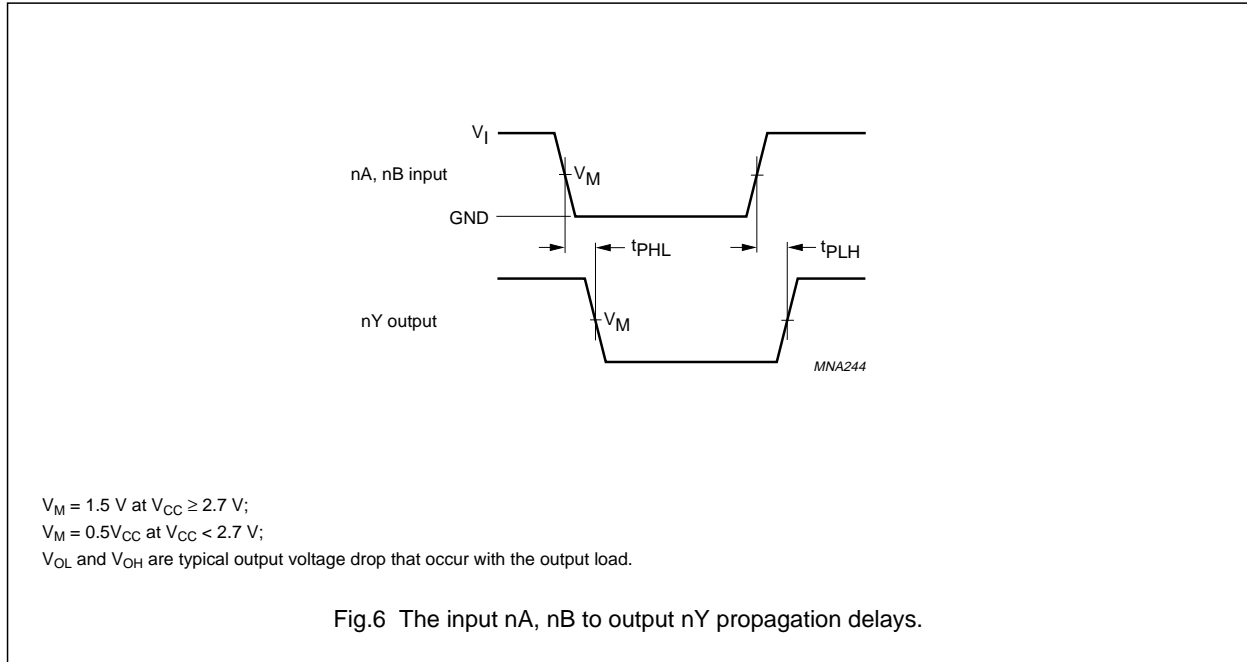
Notes

1. Typical values are measured at V_{CC} = 3.3 V.
2. Skew between any two outputs of the same package switching in the same direction. This parameter is guaranteed by design.

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AC WAVEFORMS



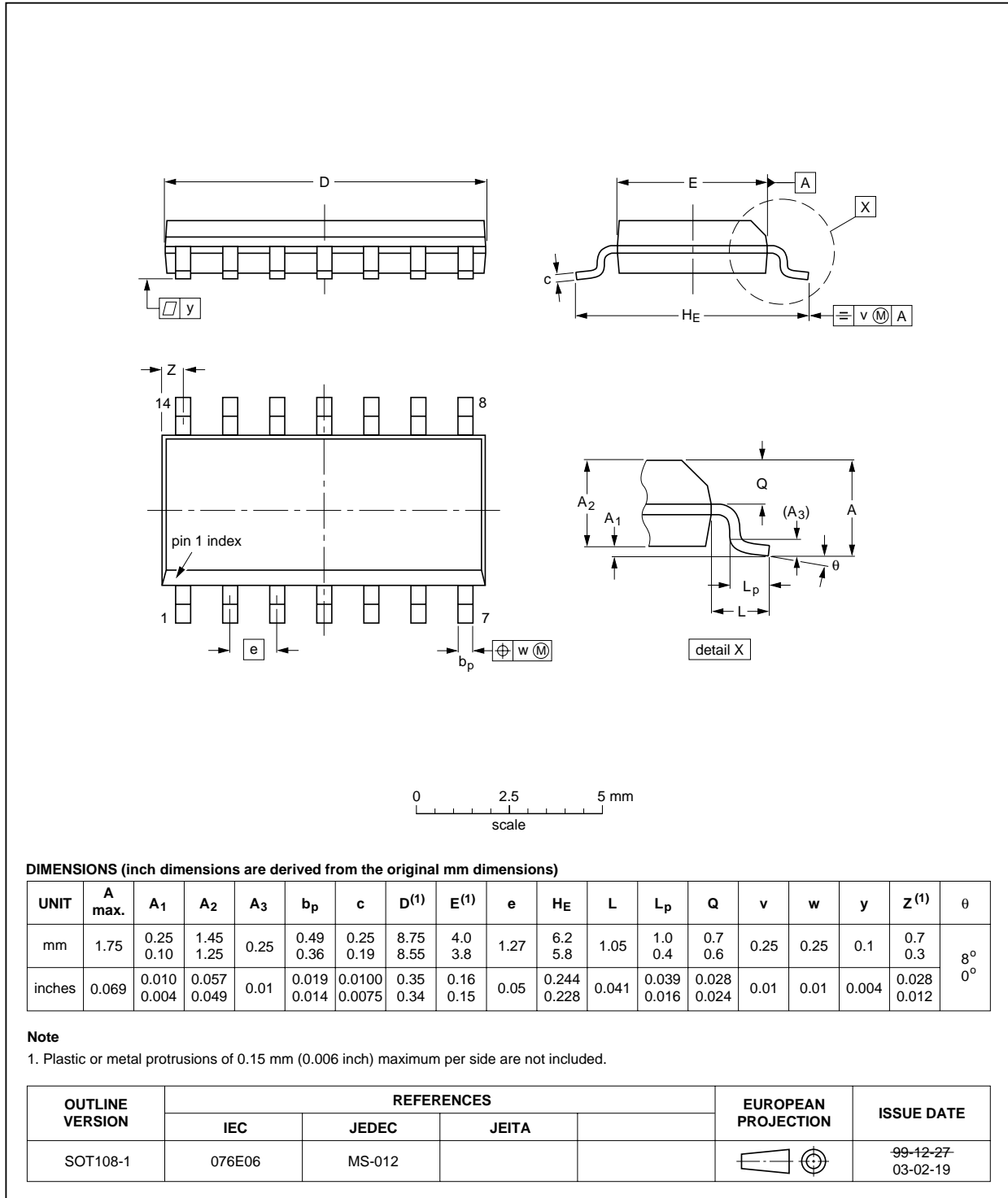
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PACKAGE OUTLINES

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1

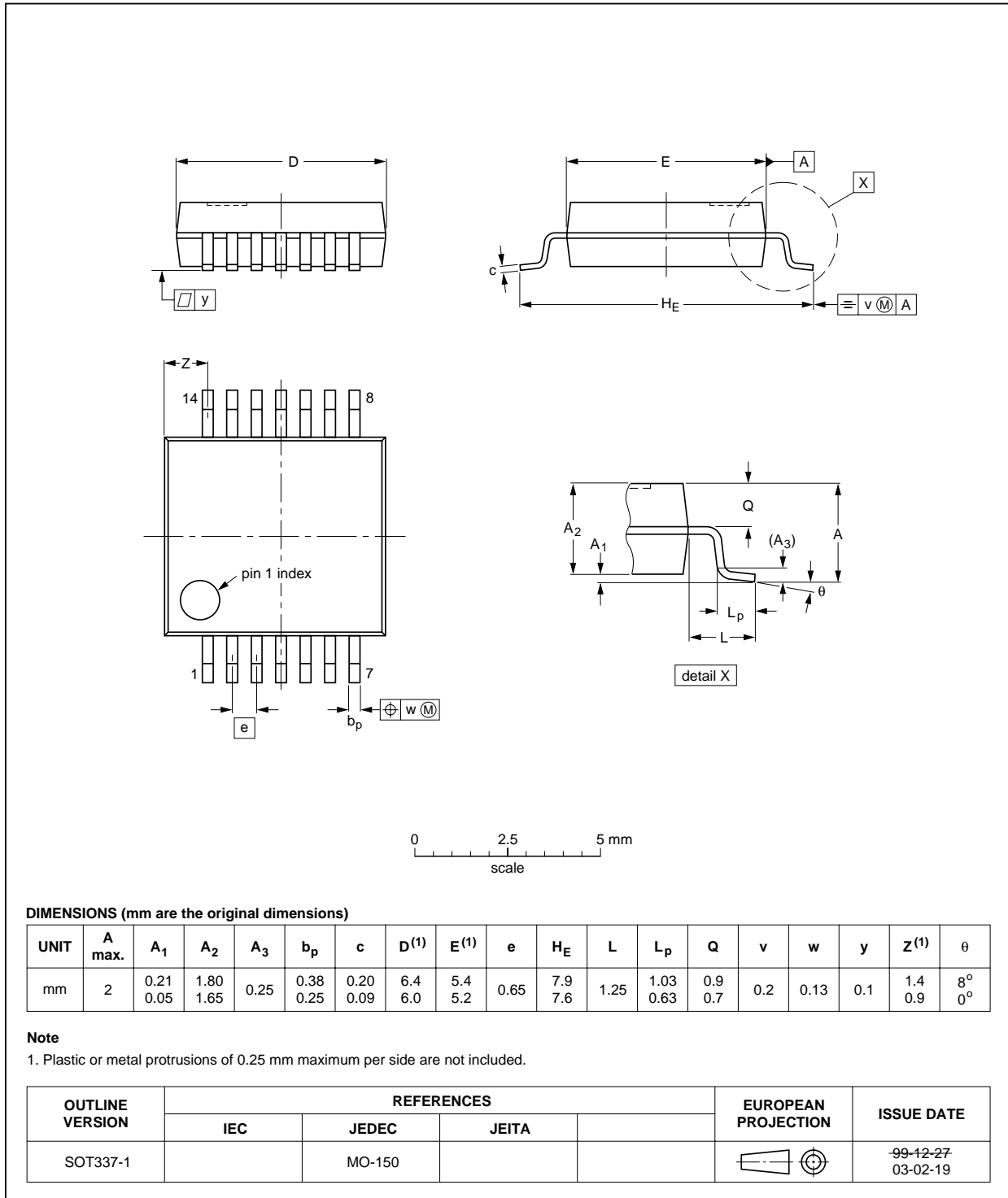


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SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1

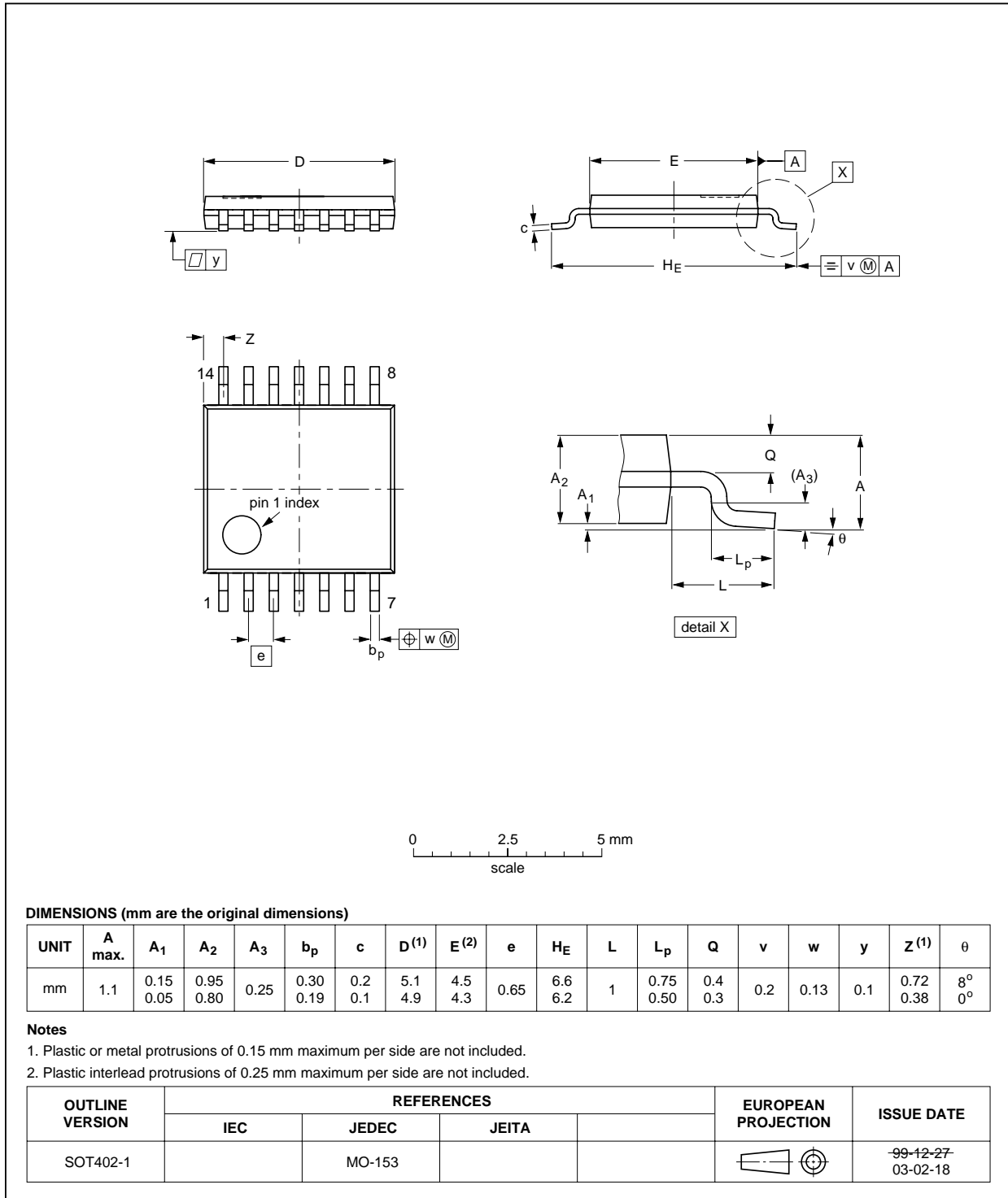


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TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1

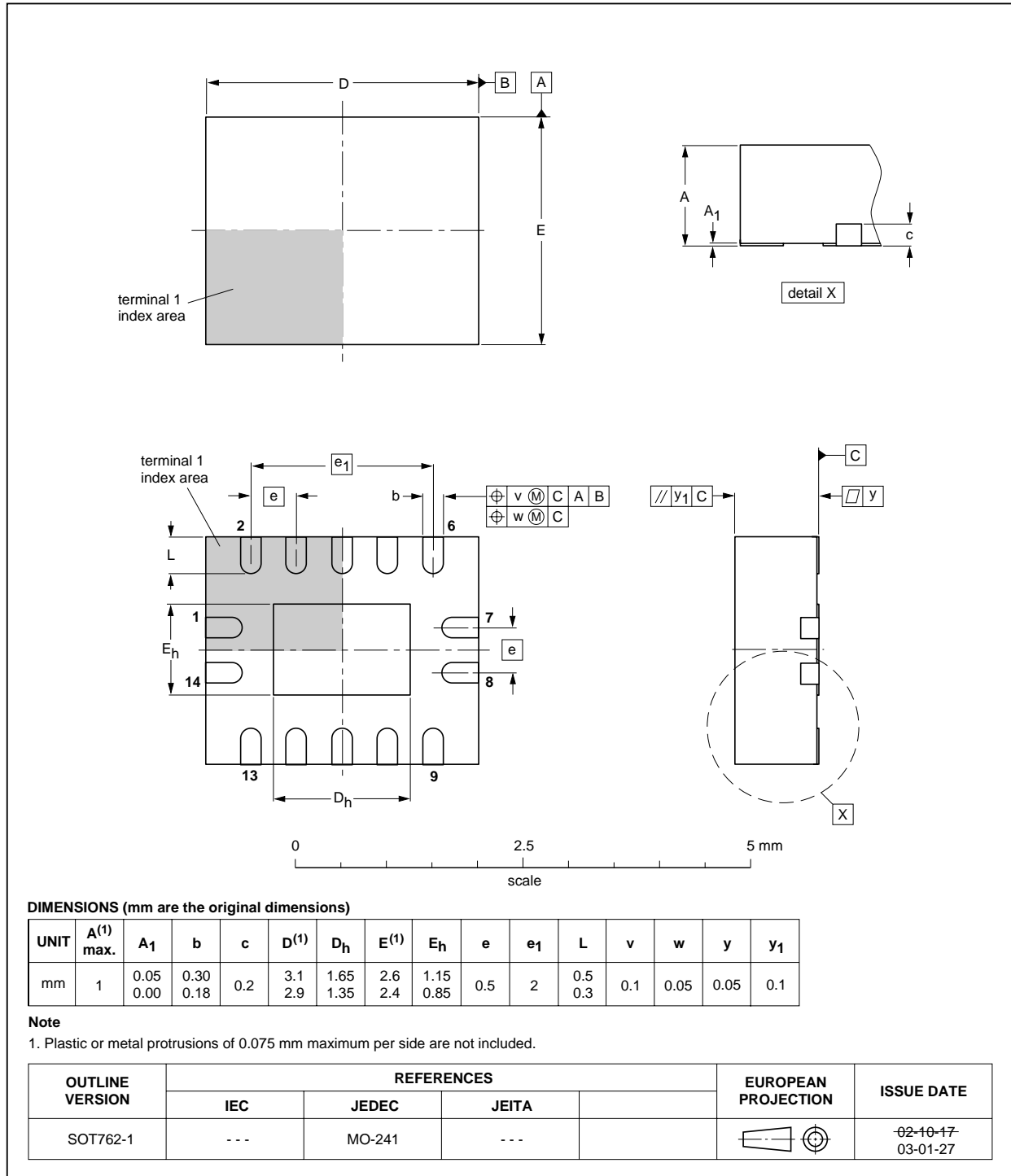


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DHVQFN14: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 x 3 x 0.85 mm

SOT762-1



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DATA SHEET STATUS

| LEVEL | DATA SHEET STATUS ⁽¹⁾ | PRODUCT STATUS ⁽²⁾⁽³⁾ | DEFINITION |
|-------|----------------------------------|----------------------------------|--|
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